



## **EPC8009ENGR Information**

Part Number EPC8009ENGR

Manufacturer EPC

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

**Description** TRANS GAN 65V 4.1A BUMPED DIE

Package Die

For the pricing/inventory/lead time, please contact

us

For Reference Only Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









# **EPC8009ENGR Specifications**

Manufacturer Part Number	EPC8009ENGR
Manufacturer	EPC
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	Die
Series	eGaN?
FET Type	N-Channel
Technology	GaNFET (Gallium Nitride)
Drain to Source Voltage (Vdss)	65V
Current - Continuous Drain (Id) @ 25°C	4.1A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	5V
Vgs(th) (Max) @ Id	2.5V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	0.38nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	47pF @ 32.5V
Vgs (Max)	+6V, -5V
FET Feature	-
Power Dissipation (Max)	-
Rds On (Max) @ Id, Vgs	138 mOhm @ 500mA, 5V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	Die
Package / Case	Die
	Report errors?

#### **EPC8009ENGR Guarantees**



### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

## **EPC8009ENGR Payment Methods**



















## **EPC8009ENGR Shipping Methods**













If you have any question about EPC8009ENGR, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com